

Description

The PPMDP15R150EL uses trench technology to provide excellent $R_{DS(on)}$ low gate charge. This device is suitable for power management and high efficiency applications at high switching frequencies applications.

MOSFET Product Summary

$V_{DS}(V)$	$R_{DS(on)}(m\Omega)(Typ)$	$I_D(A)$
-150	125@ $V_{GS} = -10V$	-15
	130@ $V_{GS} = -4.5V$	

Feature

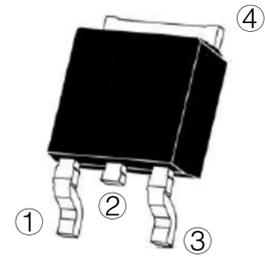
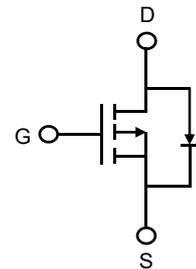
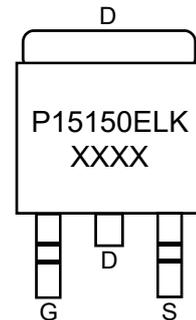
- High Power and current handling capability
- Lead free product is acquired
- Surface Mount Package

Applications

- PWM applications
- Load Switch
- Power Management
- DC-DC Converters
- Wireless Chargers

Absolute maximum rating@25°C

Rating	Symbol	Value	Units
Drain-Source Voltage	V_{DS}	-150	V
Gate-Source Voltage	V_{GS}	±20	V
Drain Current-Continuous ¹⁾	I_D	$T_C=25^\circ C$	-15
		$T_C=100^\circ C$	-9.5
Pulsed Drain Current ²⁾	I_{DM}	-60	A
Total Power Dissipation ³⁾	P_D	78	W
Avalanche Current ⁴⁾	I_{AS}	-29	A
Avalanche Energy ⁴⁾	E_{AS}	210	mJ
Thermal Resistance , Junction-to-Case ⁵⁾	$R_{\theta JC}$	1.6	°C/W
Thermal Resistance , Junction-to-Ambient ⁵⁾	$R_{\theta JA}$	37.3	°C/W
Junction and Storage Temperature Range	T_J, T_{STG}	-55 to 150	°C


TO-252 (Top View)

Circuit Diagram

Marking (Top View)

Electrical characteristics per line@25°C (unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Off Characteristics						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS} = 0V, I_D = -250\mu A$	-150	-	-	V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = -150V, V_{GS} = 0V$	-	-	-1.0	μA
Gate-Body Leakage Current	I_{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$	-	-	± 10	μA
On Characteristics						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = -250\mu A$	-1.0	-1.8	-3.0	V
Drain-Source On-State Resistance	$R_{DS(ON)}$	$V_{GS} = -10V, I_D = -20A$	-	125	150	m Ω
		$V_{GS} = -4.5V, I_D = -20A$	-	130	160	
Dynamic Characteristics⁶⁾						
Input Capacitance	C_{ISS}	$V_{DS} = -75V, V_{GS} = 0V$ $f = 1MHz$	-	2860	-	pF
Output Capacitance	C_{OSS}		-	103	-	
Reverse Transfer Capacitance	C_{RSS}		-	66	-	
Switching Characteristics⁶⁾						
Turn-on Delay Time	$t_{d(on)}$	$V_{DS} = -75V, V_{GS} = -10V,$ $R_G = 10\Omega, I_D = -20A$	-	8	-	ns
Turn-on Rise Time	t_r		-	31	-	
Turn-Off Delay Time	$t_{d(off)}$		-	126	-	
Turn-Off Fall Time	t_f		-	54	-	
Total Gate Charge	Q_g	$V_{DS} = -75V, V_{GS} = -10V,$ $I_D = -20A$	-	60	-	nC
Gate-Source Charge	Q_{gs}		-	12	-	
Gate-Drain Charge	Q_{gd}		-	7	-	
Gate Resistance	R_g	$V_{GS} = 0V, V_{DS} = 0V, f = 1MHz$	-	5	-	Ω
Drain-Source Diode Characteristics						
Diode Forward Voltage	V_{SD}	$V_{GS} = 0V, I_S = -20A$	-	-0.9	-1.2	V
Reverse Recovery Time	t_{rr}	$I_F = -20A, di/dt = 100A/\mu s$	-	67	-	ns
Reverse Recovery Charge	Q_{rr}		-	167	-	nC

Notes:

1. Computed continuous current assumes the condition of T_{J_Max} while the actual continuous current depends on the thermal & electro-mechanical application board design.
2. Repetitive Rating: Pulse width limited by maximum junction temperature($T_{J_Max} = 150^\circ C$).
3. Pulse Test: Pulse Width $\leq 10\mu s$, Duty Cycle $\leq 1\%$.
4. This single-pulse measurement was taken under the following condition [$L = 0.5mH, V_{GS} = -10V, V_{DS} = -75V$]while it's value is limited by $T_{J_Max} = 150^\circ C$.
5. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper pad layout.
6. Guaranteed by design, not subject to production.

Typical Characteristics

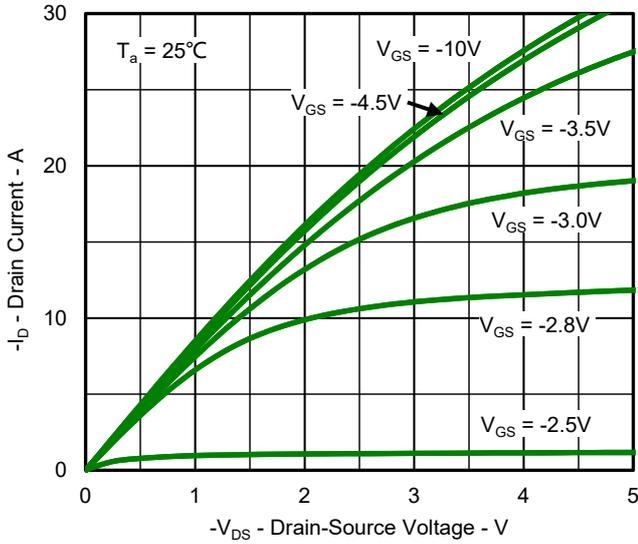


Fig.1 Output Characteristics

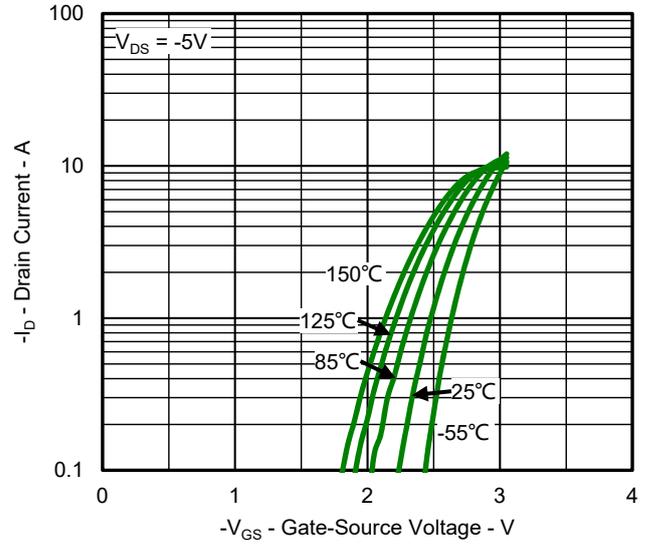


Fig.2 Typical Transfer Characteristic

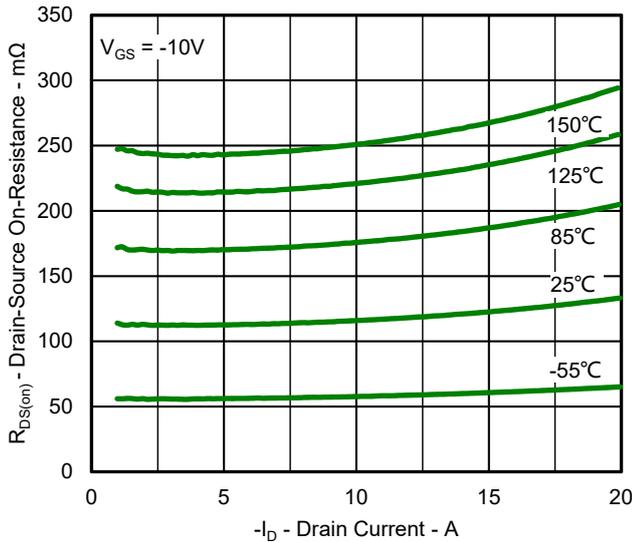


Fig.3 Typical On-Resistance vs Drain Current and Temperature

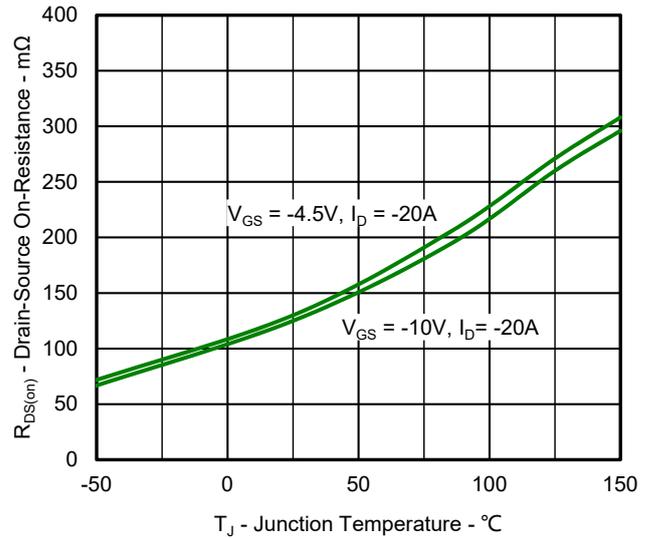


Fig.4 On-Resistance Variation with Temperature

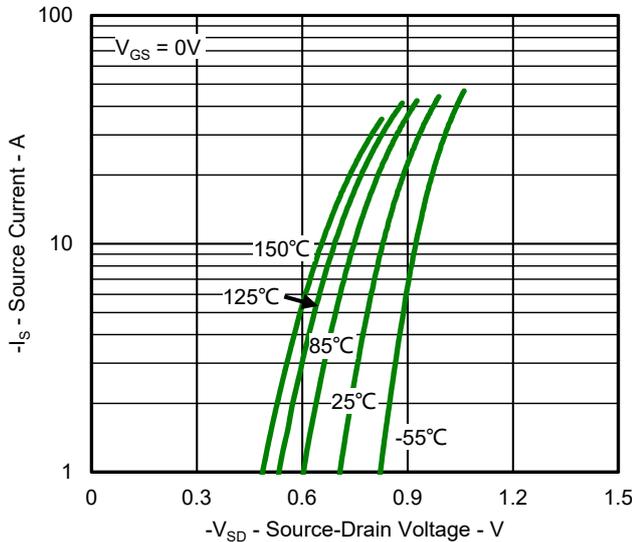


Fig.5 Diode Forward Voltage vs. Current

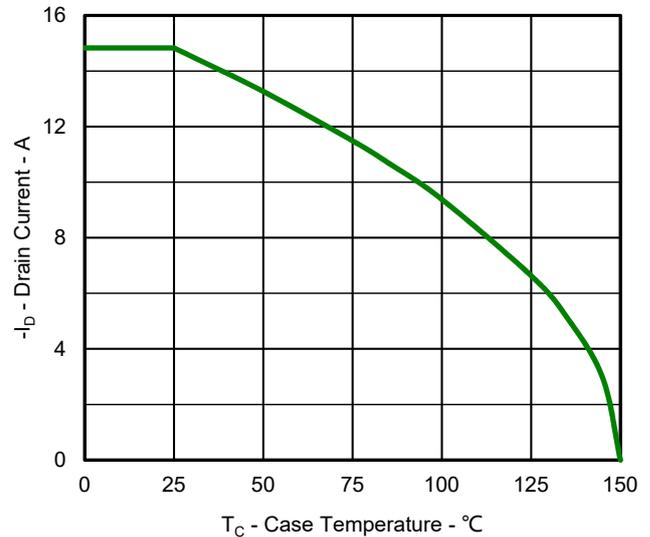


Fig.6 Maximum Drain Current vs. Case Temperature

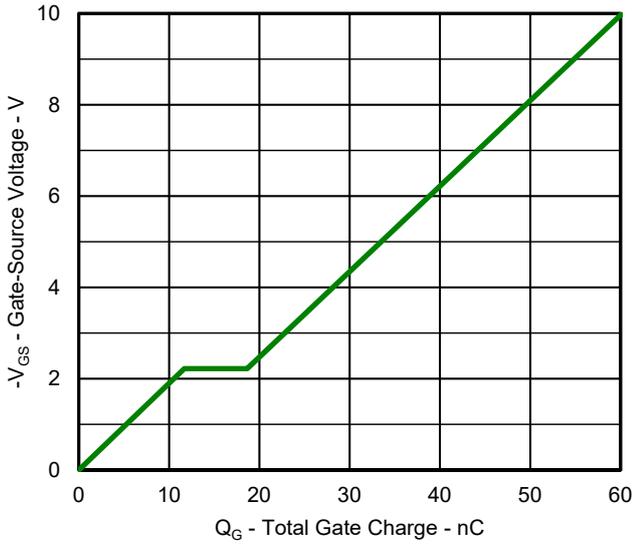


Fig.7 Gate Charge Characteristics

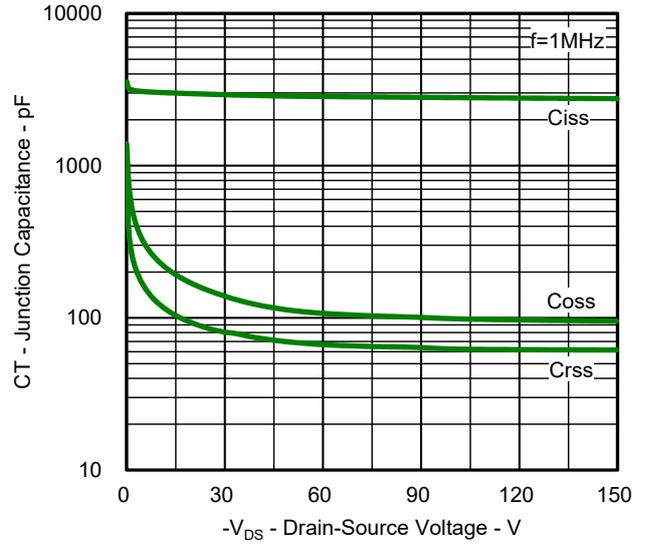


Fig.8 Typical Junction Capacitance

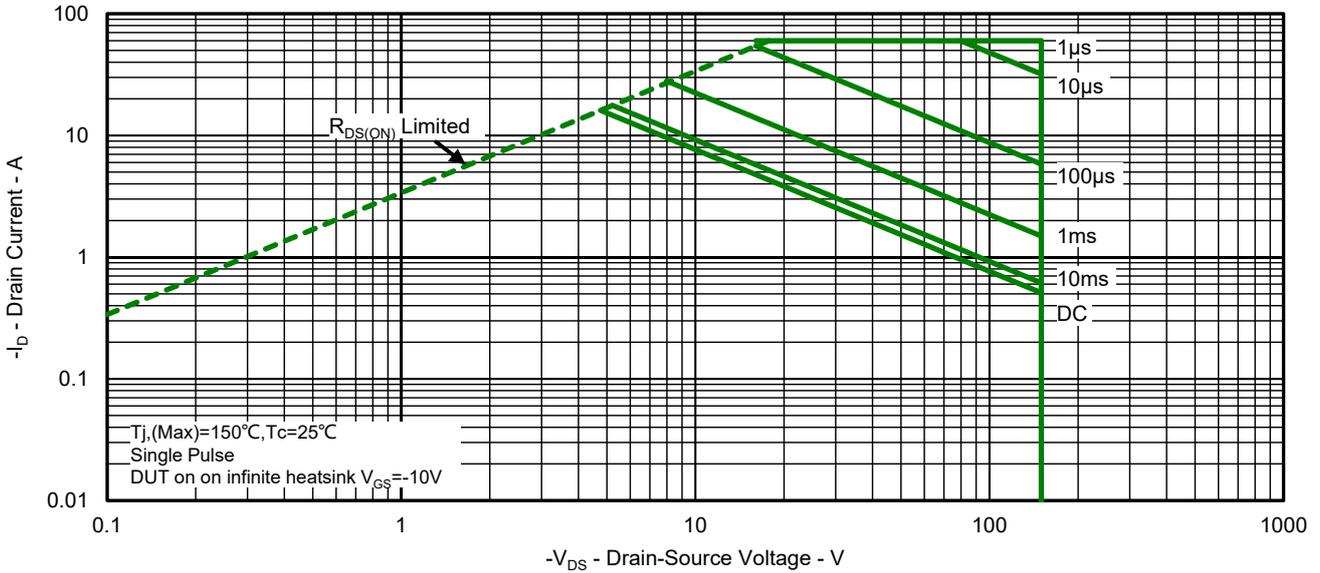


Fig.9 Safe Operation Area

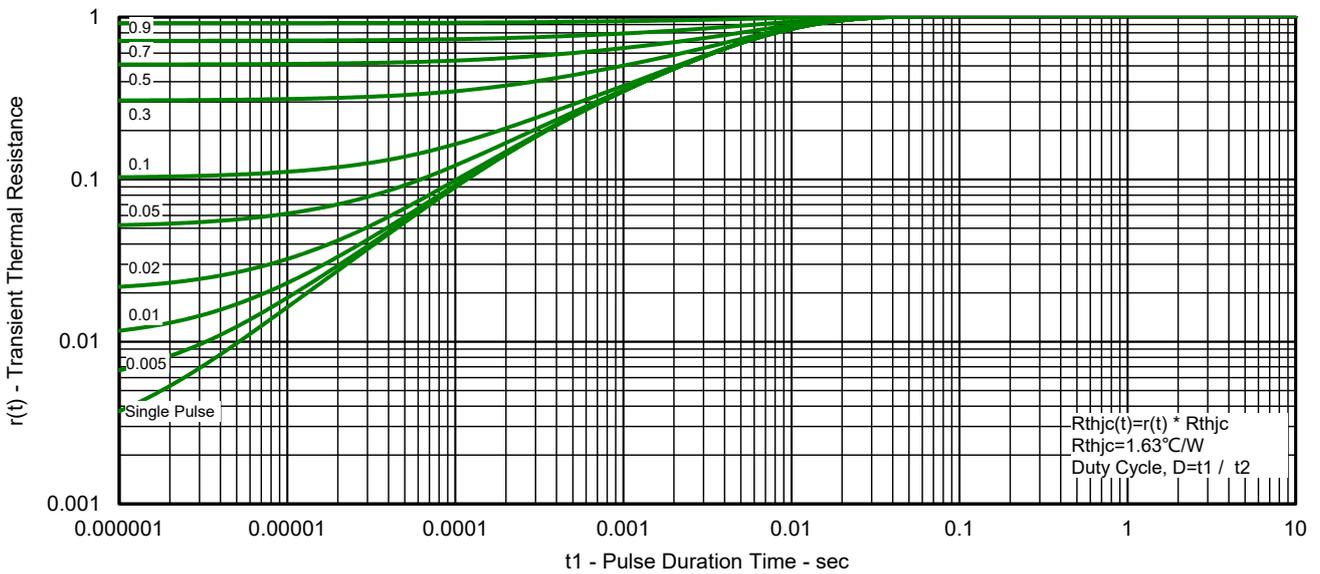
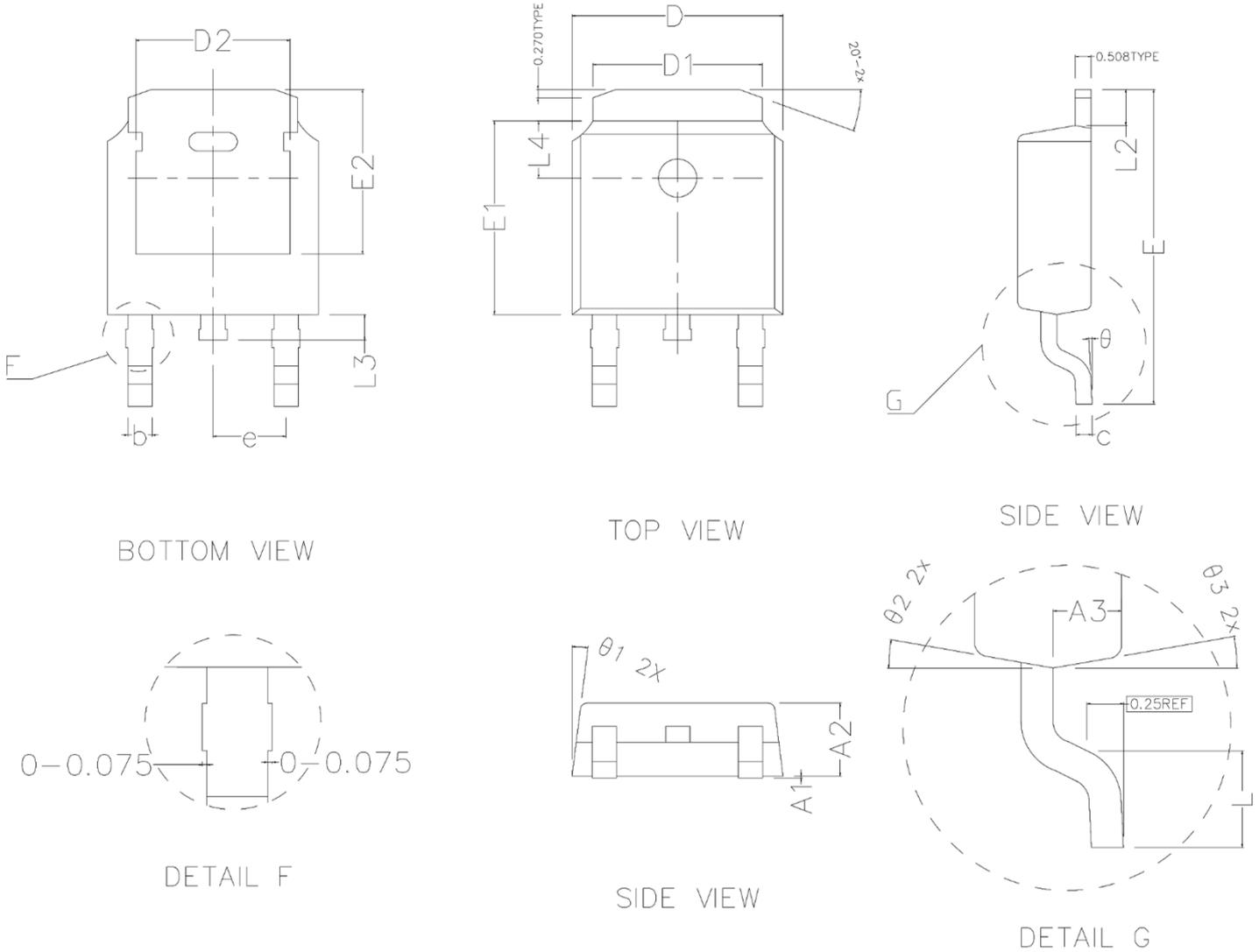


Fig.10 Transient Thermal Resistance

Product Dimension (TO-252)



Dim	Millimeters		Inches		Dim	Millimeters		Inches	
	Min	Max	Min	Max		Min	Max	Min	Max
A1	0.03	0.13	0.001	0.005	E2	5.14 Ref.		0.202 Ref.	
A2	2.20	2.40	0.087	0.094	e	2.286 Typ.		0.090 Typ.	
A3	0.96	1.06	0.038	0.042	L	1.40	1.60	0.055	0.063
b	0.64	0.74	0.025	0.029	L2	1.00 Ref.		0.039 Ref.	
c	0.46	0.55	0.018	0.022	L3	0.80 Ref.		0.031 Ref.	
D	6.50	6.70	0.256	0.264	L4	1.80 Ref.		0.071 Ref.	
D1	5.334 Ref.		0.210 Ref.		θ	0°	8°	0°	8°
D2	4.83 Ref.		0.190 Ref.		θ1	7° Typ.		7° Typ.	
E	9.77	10.17	0.385	0.400	θ2	7° Typ.		7° Typ.	
E1	6.00	6.20	0.236	0.244	θ3	7° Typ.		7° Typ.	

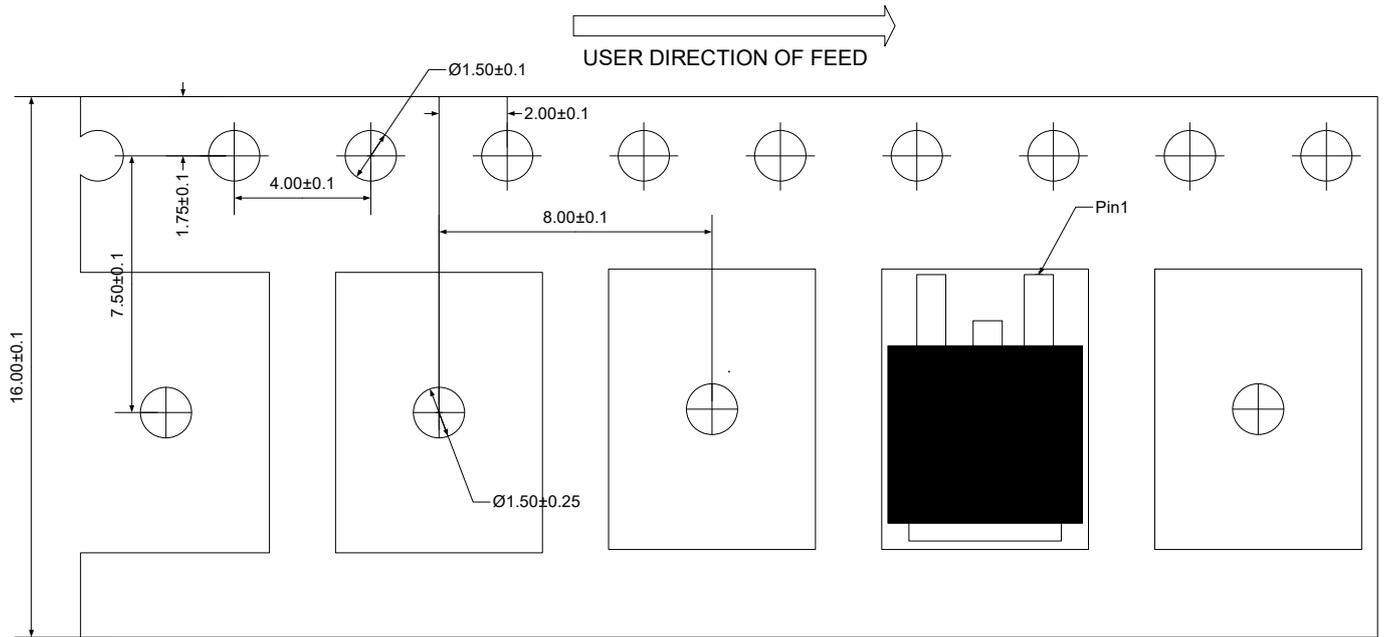
P-Channel MOSFET

PPMDP15R150EL

Ordering Information

Package	Reel	Shipping
TO-252	13"	2500 / Tape & Reel

Load With Information



Unit:mm

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